

# Abhinav Gorthy

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## EDUCATION

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- **University of Cincinnati** Cincinnati, OH  
• **Ph.D. in Electrical Engineering** Aug 2025 - Present  
**Coursework:** VLSI Design, VLSI Test and Low Power Design, VLSI Design Automation, Computer Architecture, Nanoelectric Devices, Intelligent Systems, Trust in Digital Hardware
- **University of Cincinnati** Cincinnati, OH  
• **Master of Science in Electrical Engineering** (GPA: 3.4/4.0) Aug 2023 - July 2025  
**MS Thesis:** A Comparative Study of HfO<sub>2</sub>/MgO Charge Trap Flash Memory and OHP/DNA RRAMs
- **Jawaharlal Nehru Technological University** Hyderabad, India  
• **Bachelor of Technology in Electronics and Communications Engg.** (GPA: 8.4/10) Aug 2019 - Jun 2025

## SKILLS

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- **Programming and Scripting Languages:** Python, C, C++, Verilog HDL, VHDL, TCL
- **EDA Tools:** Synopsys HSPICE, Design Compiler, ICC II, TetraMAX, TCAD Sentaurus, Cadence Virtuoso, Xcelium, Genus, Innovus, OpenLane
- **Cleanroom Experience:** Wafer cleaning, Oxidation, RIE, PVD, Photolithography, Wet Etching
- **Equipment Expertise:** Keithley 4200-SCS Parameter Analyzer, Cascade Probe Station, Lakeshore Cryotronics Cryogenic Probe Station, AJA Orion Sputtering System, March CS-1701 RIE, Nanonex NX-2600 Lithography
- **Technical Knowledge:** Analog IC Design & Verification, Custom Layout Design (Full-Custom & Semi-Custom), Memory Circuit Design (SRAM, DRAM, NAND), RTL-to-GDSII Flow, Low-Power Design Techniques

## PROFESSIONAL EXPERIENCE

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**Graduate Research Assistant - MIND Lab, UC (Advisor: Dr. Rashmi Jha)** **Oct 2023 - Present**

### Device Characterization and Reliability Analysis

- Conducted electrical characterization (C-V, I-V, frequency-dependent analysis, endurance, and retention) of charge trap flash memory and RRAM devices using Keithley 4200A-SCS Semiconductor Parameter Analyzer.
- Performed reliability and failure analysis testing protocols, including temperature-based retention, BTI and TDDDB using a Lakeshore Cryogenic Probe Station.
- Performed heavy ion radiation experiments on TaO<sub>x</sub> RRAM devices and involved in Focused Ion Beam (FIB) cross-section preparation, TEM/EDS analysis to assess structural degradation.
- Investigated conduction mechanisms by fitting experimental results to physics-based equations and executed statistical data analysis using Python.

### Device Fabrication

- Implemented Design of Experiments (DoE) to optimize TaO<sub>x</sub> RRAM stacks with Cu active electrodes, achieving high  $R_{ON}/R_{OFF} > 10^3$  at low operating voltages ( $< 1$  V) with multi-state switching capability.
- Performed photolithography for top electrodes on 4-inch Si wafers (device areas: 30–150  $\mu\text{m}^2$ ) with 97% yield and developed wet etching recipes for metals and insulators.
- Collaborated with Penn State University to fabricate biocompatible RRAMs using OHP and DNA layers, advancing towards CMOS-compatible integration.

### Device Modeling and Circuit Simulations

- Simulated two-terminal Charge Trap Flash memory stack (W/MgO/HfO<sub>2</sub>/MgO/p-Si) in TCAD Sentaurus using trapping and tunneling models and analyzed capacitance shifts and evaluated endurance and retention
- Developed sweep-based and pulse-based RRAM models in Verilog-A from experimental data.
- Designed a 4×4 1T-1R RRAM crossbar in Cadence Virtuoso with integrated selection circuitry and voltage-latched sense amplifiers.
- Working towards tape-out with heterogeneous integration of bio-compatible RRAMs and custom readout circuits.

## PROJECTS

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### Design and Layout of 64 Bit SRAM (Tools: Cadence Virtuoso; PDK : gpd45nm)

Oct 2024

- Designed a 64 bit SRAM array (8x8) using optimized 6T bitcells and integrated custom row/column decoders and sense amplifiers.
- Validated read/write operations through transient and steady-state simulations in ADE Explorer.
- Developed entire layout in Layout XL and ensured design integrity with LVS, DRC checks, and parasitic extraction using ASSURA and QUANTUS

### RTL-to-GDSII Implementation of a CPU Macro (Tools: OpenLane EDA; PDK: Skywater 130nm) June 2024

- Synthesized Verilog code for PICORV32A (VSD CPU Macro) and completed its physical design using OpenLane TCL scripts and developed design constraints.
- Created a custom cell, extracted a SPICE file to measure input/output slew and delay, and generated a LEF file to integrate the cell into the design flow.
- Achieved positive setup & hold slack in timing analysis through ECO strategies.

### Development of VLSI Partitioning, Placement, and Routing Tools (Tools: Visual Studio Code) Feb 2024

- Developed a C++ tool for two-way bipartitioning using the Kernighan-Lin heuristic, tested on netlists up to 40,000 cells and 4,000,000 nets.
- Implemented placement and routing algorithms based on force-directed placement and channel routing, validated on benchmarks with up to 2,000 cells and nets.

### Square Root Machine Synthesis with DFT (Tools: Design Compiler, TetraMAX, ModelSim) March 2024

- Synthesized a gate-level netlist of a square root machine using Verilog with SAED 90nm PDK and inserted scan chains into the design using TCL
- Generated test patterns and extracted RTL switching activity data using ModelSim to produce a VCD (Value Change Dump) file, converting it to SAIF (Switching Activity Interchange Format) for power estimation.
- Achieved 99.08% fault coverage using TetraMAX, optimizing timing, area, and power metrics pre and post-scan insertion.

### Bit-Sliced 4-Bit First in First Out (FIFO) (Tools: ModelSim, HSPICE, IRSIM, Magic VLSI) Nov 2023

- Designed a tape-out-ready 4-bit FIFO chip (60-bit slices) using ON C5 0.5μm n-well CMOS process, clocked at 100 MHz for efficient push/pop operations.
- Developed VHDL code and test bench; included standard cell delays for practical waveform simulation.
- Executed an optimized custom layout using M1, M2 metal interconnects with zero DRC errors; performed LVS check by extracting to SPICE and calculated propagation delays.

## PUBLICATIONS

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- Keremane, K.S., **Gorthy, A.**, Zheng, L., Ravi, C.C., Wu, H., Yennawar, N.H., Priya, S., Jha, R., Poudel, B., “Molecularly Engineered Highly Stable Memristors with Ultra-Low Operational Voltage: Integrating Synthetic DNA with Quasi-2D Perovskites”, *Nature Materials*, manuscript under review.
- **A. Gorthy**, V. K. Gogi, R. Srinivasan, J. Mayersky, K. Leedy, and R. Jha, “Thickness Dependent Analysis of Ultra-Thin MgO Tunneling and Blocking Layers in HfO<sub>2</sub> Charge Trap Flash Memory”, *Journal of Applied Physics*, manuscript under preparation.
- S. Gollapudi\*, **A. Gorthy\***, V. K. Gogi, R. Srinivasan, and R. Jha, “Stability Study of BEOL-Compatible Forming-Free TaO<sub>x</sub> RRAM Devices Under Extreme Temperature and Radiation Conditions”, *IEEE Access*, manuscript under preparation.

## PATENTS

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- IoT-Based Modern Food Service System (Indian Patent Application Number - 202341060583)
- The Automated Titrator (Indian Patent Application Number - 202141061676)